

T498A474K035ZTE10K

Obsolete

B45196P, Tantalum, MnO₂ Tantalum, High Temperature, .47 uF, 10%, 35 VDC, SMD, Molded, High Temperature, N/A, 10 Ohms, 3216, Height Max = 1.8mm



General Information

Series	B45196P
Dielectric	MnO ₂ Tantalum
Style	SMD Chip
Description	SMD, Molded, High Temperature
Features	High Temperature
RoHS	Yes
Termination	Tin
AEC-Q200	No
Notes	Obsolete. Old Part Number [Obsolete] Was B45196P6474K109.

Specifications

Capacitance	.47 uF
Capacitance Tolerance	10%
Voltage DC	35 VDC (85C), 27.89 VDC (125C), 23.45 VDC (150C)
Temperature Range	-55/+150°C
Rated Temperature	85°C
Dissipation Factor	3%
Failure Rate	N/A
Resistance	10 Ohms (100kHz)
Leakage Current	0.5 uA

Dimensions

Footprint	3216
L	3.2mm +/-0.2mm
W	1.6mm +/-0.2mm
H	1.6mm +/-0.2mm
S	0.8mm +/-0.3mm
F	1.2mm +/-0.1mm
K	1.3mm TYP

Packaging Specifications

Packaging	T&R, 178mm
Packaging Quantity	2000